## NSN 5961-01-319-0470

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-319-0470 **Inclosure Material:** Plastic **Overall Length:** 20.0 millimeters **Terminal Length:** 20.0 millimeters **Overall Height:** 4.8 millimeters **Overall Width:** 15.6 millimeters **Function For Which Designed:** Switching **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Terminal and unthreaded hole Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 900.0 collector to base voltage/static/emitter open and 800.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 6.00 amperes source cutoff current and 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector **Transfer Ratio:** 8.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life:

Demilitarization: No

**Unit Of Measure:** 

N/a

## **NSN 5961-01-319-0470** Transistor - Page 2 of 2



Fiig:

A110a0